

20A Avg.

80 Volts

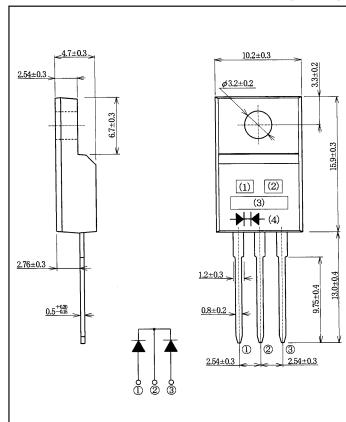
SBD

FCHS20U08

■最大定格 Maximum Ratings

Item	Symbol	Conditions			Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	V _{RRM}	80			V
平均整流電流 Average Rectified Forward Current	I _O	50Hz, 正弦全波通電抵抗負荷 50Hz Full Sine Wave Resistive Load	T _c =116°C V _{RRM} =40V	20	A
実効順電流 R.M.S. Forward Current	I _{F(RMS)}	22.2			A
サージ順電流 Surge Forward Current	I _{FSM}	180 50Hz正弦全波, 1サイクル, 非くり返し 50Hz Full Sine Wave, 1cycle, Non-repetitive			A
動作接合温度範囲 Operating Junction Temperature Range	T _{jw}	−40~+150			°C
保存温度範囲 Storage Temperature Range	T _{stg}	−40~+150			°C
締付トルク Mounting torque	F _{tor}	推奨値 Recommended Value	0.5	N·m	

■OUTLINE DRAWING(mm)



■APPROX. NET WEIGHT:1.80g

■電気的・熱的特性 Electrical/Thermal Characteristics

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
ピーカー逆電流 Peak Reverse Current	I _{RM}	T _j =25°C, V _{RRM} =V _{RRM} , 一素子あたり Per Diode	—	—	150	μA
ピーカー順電圧 Peak Forward Voltage	V _{FM}	T _j =25°C, I _{FM} =10 A, 一素子あたり Per Diode	—	—	0.75	V
熱抵抗 Thermal Resistance	R _{th(j-c)}	接合部・ケース間 Junction to Case	—	—	2.0	°C/W
	R _{th(c-f)}	ケース・フィン間 Case to Fin	—	—	1.5	°C/W

■定格・特性曲線

FIG.1

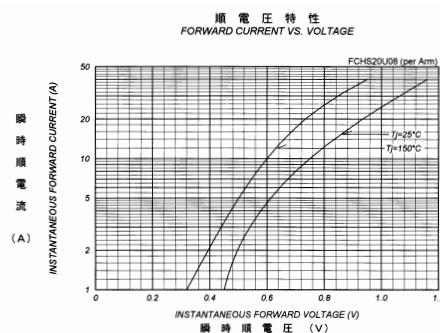


FIG.2

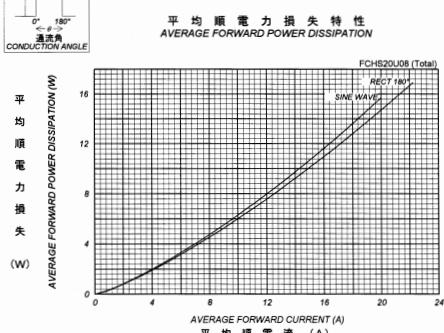


FIG.3

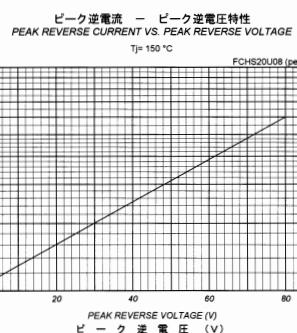


FIG.4

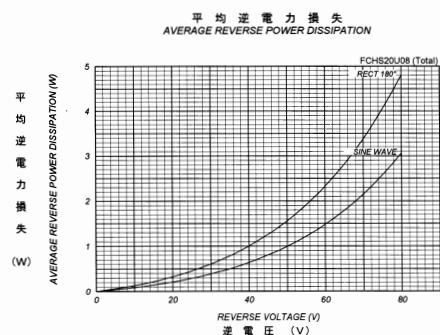


FIG.5

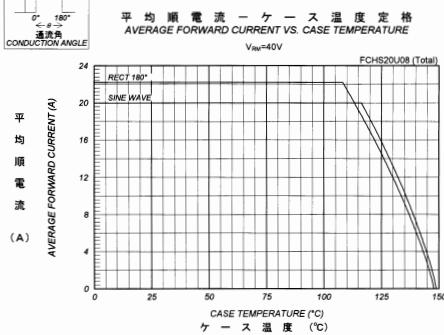


FIG.6

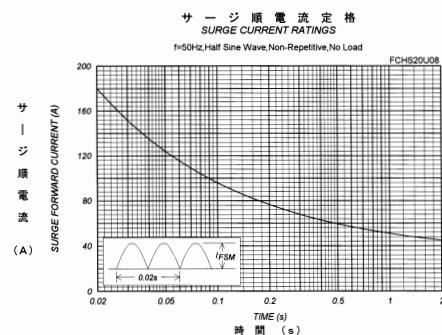


FIG.7

